

To all our customers

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Renesas Technology Corp.
Customer Support Dept.
April 1, 2003

Cautions

Keep safety first in your circuit designs!

1. Renesas Technology Corporation puts the maximum effort into making semiconductor products better and more reliable, but there is always the possibility that trouble may occur with them. Trouble with semiconductors may lead to personal injury, fire or property damage.

Remember to give due consideration to safety when making your circuit designs, with appropriate measures such as (i) placement of substitutive, auxiliary circuits, (ii) use of nonflammable material or (iii) prevention against any malfunction or mishap.

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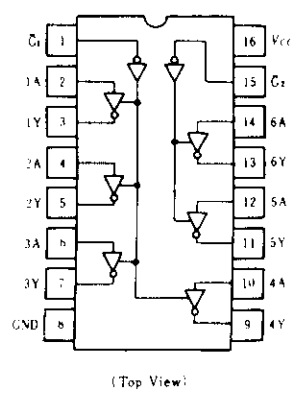
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HD74LS368A ●Hex Bus Drivers (inverted data outputs with three-state outputs)

PIN ARRANGEMENT



ABSOLUTE MAXIMUM RATINGS

Item	Symbol	Ratings	Unit
Supply voltage	V_{CC}	7.0	V
Input voltage	V_{IS}	7.0	V
Output voltage (off-state)	$V_{O(off)}$	5.5	V
Operating temperature range	T_{op}	-20 ~ +75	°C
Storage temperature range	T_{stg}	-65 ~ +150	°C

FUNCTION TABLE

$\bar{G}$	A	Y
H	X	Z
L	L	H
L	H	L

Note) H: high level, L: low level,
X: irrelevant
Z: off (high-impedance) state
of a 3-state output

RECOMMENDED OPERATING CONDITIONS

Item	Symbol	min	typ	max	Unit
Output current	I_{OH}	—	—	-2.6	mA
Output current	I_{OL}	—	—	24	mA

■ ELECTRICAL CHARACTERISTICS ($T_a = -20 \sim +75^\circ\text{C}$)

Item	Symbol	Test Conditions	min	typ*	max	Unit	
Input voltage	V_{IH}		2.0	—	—	V	
	V_{IL}		—	—	0.8		
Output voltage	V_{OH}	$V_{CC}=4.75\text{V}$, $V_{IH}=2\text{V}$, $V_{IL}=0.8\text{V}$, $I_{OH}=-2.6\text{mA}$	2.4	—	—	V	
	V_{OL}	$V_{CC}=4.75\text{V}$, $V_{IH}=2\text{V}$, $V_{IL}=0.8\text{V}$	$I_{OL}=12\text{mA}$	—	—		0.4
			$I_{OL}=24\text{mA}$				0.5
Output current	I_{OZ}	$V_{CC}=5.25\text{V}$, $V_{IH}=2\text{V}$, $V_{IL}=0.8\text{V}$	$V_O=2.4\text{V}$	—	—	20	μA
			$V_O=0.4\text{V}$	—	—	-20	
Input current		I_{IH}	$V_{CC}=5.25\text{V}$, $V_I=2.7\text{V}$	—	—	20	μA
	A inputs	I_{IL}	$V_{CC}=5.25\text{V}$, $V_I=0.5\text{V}$, $\bar{G}$ input at 2V	—	—	-20	μA
			$V_{CC}=5.25\text{V}$, $V_I=0.4\text{V}$, $\bar{G}$ inputs at 0.4V	—	—	-0.4	mA
	$\bar{G}$ inputs	$V_{CC}=5.25\text{V}$, $V_I=0.4\text{V}$	—	—	-0.4		
		I_I	$V_{CC}=5.25\text{V}$, $V_I=7\text{V}$	—	—	0.1	mA
Short-circuit output current	I_{OS}	$V_{CC}=5.25\text{V}$	-40	—	-225	mA	
Supply current **	I_{CC}	$V_{CC}=5.25\text{V}$	—	12	21	mA	
Input clamp voltage	V_{IK}	$V_{CC}=5.25\text{V}$, $I_{IH}=-18\text{mA}$	—	—	-1.5	V	

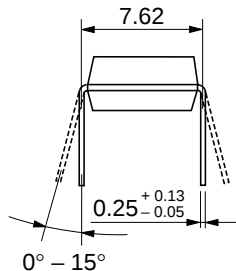
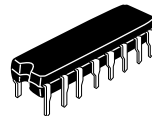
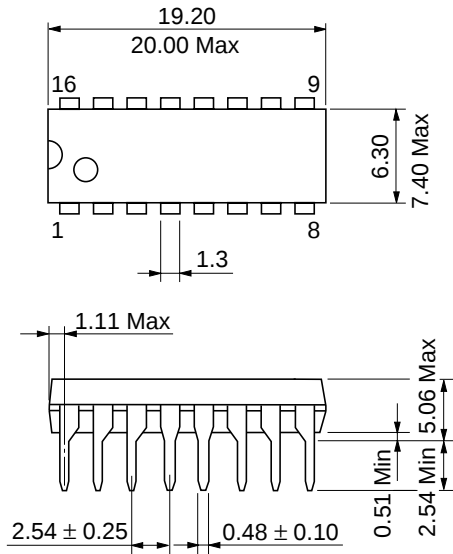
* $V_{CC} = 5\text{V}$, $T_a = 25^\circ\text{C}$

** With all outputs open, I_{CC} is measured with all inputs grounded and all $\bar{G}$ inputs at 4.5V.

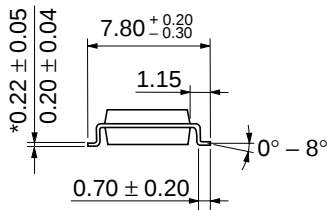
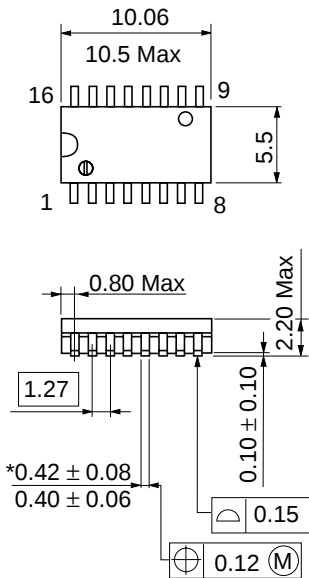
■ SWITCHING CHARACTERISTICS ($V_{CC} = 5\text{V}$, $T_a = 25^\circ\text{C}$)

Item	Symbol	Test Conditions	min	typ	max	Unit
Propagation delay time	t_{PLH}	$C_L = 45\text{pF}$, $R_L = 667\Omega$	—	7	15	ns
	t_{PHL}		—	12	18	
Output enable time	t_{ZH}		—	18	35	
	t_{ZL}		—	28	45	
Output disable time	t_{HZ}	$C_L = 5\text{pF}$, $R_L = 667\Omega$	—	—	32	ns
	t_{LZ}		—	—	35	

Note) Refer to Test Circuit and Waveform of the Common Item

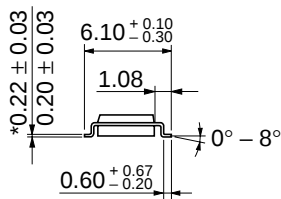
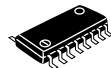
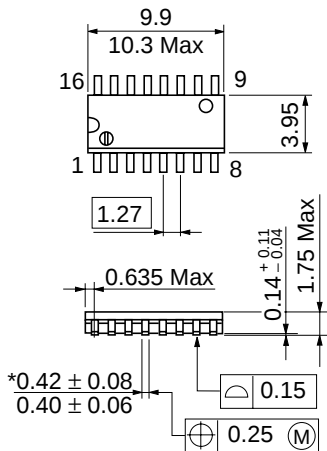


Hitachi Code	DP-16
JEDEC	Conforms
EIAJ	Conforms
Weight (reference value)	1.07 g



*Dimension including the plating thickness
Base material dimension

Hitachi Code	FP-16DA
JEDEC	—
EIAJ	Conforms
Weight (reference value)	0.24 g



*Dimension including the plating thickness
Base material dimension

Hitachi Code	FP-16DN
JEDEC	Conforms
EIAJ	Conforms
Weight (reference value)	0.15 g

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